

小型微片 固体激光器

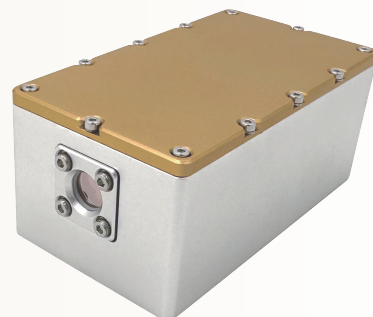
Small microchip solid-state laser



特点 Characteristic

具有高能量、窄脉宽等特点，可以作为种子用于 Mopa放大、拉曼光谱、LIBS诱导击穿光谱、激光诱导荧光，激光测距等

It has the characteristics of high energy and narrow pulse width, and can be used as a seed for Mopa amplification, Raman spectroscopy, LIBS induced breakdown spectroscopy, laser induced fluorescence, laser ranging, etc



优势 Superiority

- 高能量、窄脉宽 High energy, narrow pulse width
- 寿命长、光束质量好 Long service life and good beam quality
- 输出稳定性一致性好，能量波动小 Good output stability and consistency, with small energy fluctuations
- 性能指标接受定制，并提供全套解决方案 Performance indicators can be customized and provide a complete set of solutions

参数 Data sheet

技术指标 Technical Indicators	微片固体激光器 Microchip solid-state laser			
波长/wavelength (nm)	1064	532	355	266
单脉冲能量/Single pulse energy (mJ)	<5	<2.5	<1.25	<0.63
平均功率/Average power (mW)	<500	<250	<125	<63
脉冲宽度/Pulse width (ps)	350-1000 (Customizable)			
重复频率/Repetition frequency (Hz)	1-100			
发散角/Divergence angle (mrad)	≤10			
光束质量/Beam quality M ²	≤2			
光斑模式/Spot mode	TEM ₀₀			
偏振态/Polarization state	Random polarization/linear polarization (extinction ratio>100:1)			
能量稳定性/Energy stability RMS (%)	≤2%			
输入功率/Input power (W)	<300			
制冷量/Refrigeration capacity (W)	<50			
工作环境温度/Working environment temperature (°C)	10-35			
工作环境湿度/Working environment humidity (%)	<60			
激光器冷却介质/Laser cooling medium	Deionized water, distilled water, purified water			

